

GP1A33R

OPIC Photointerrupter with Encoder Function

Features

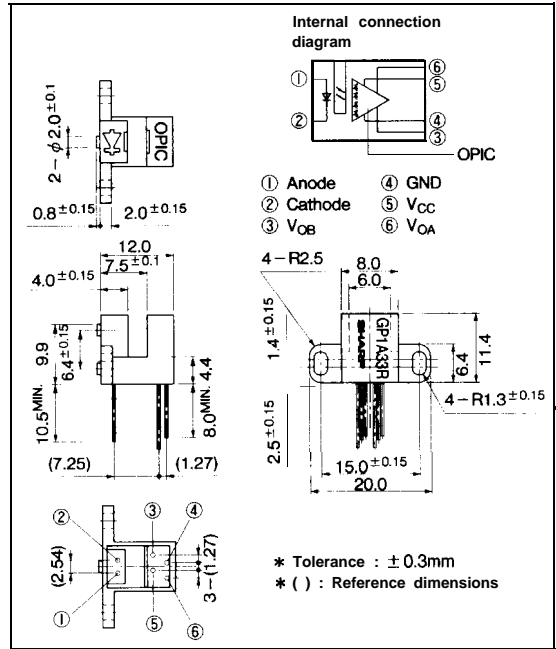
1. 2-phase (A, B) digital output
2. Capable of using plastic disk
3. Sensing accuracy
(Disk slit pitch: 1.14mm)
4. TTL compatible
5. Compact and light

Applications

1. Electronic typewriters, printers
2. Robots
3. Numerical control machines

Outline Dimensions

(Unit : mm)



* "OPIC" (optical IC) is a trademark of the SHARP Corporation
An OPIC consists of a light-detecting element and signal processing circuit integrated onto a single chip.

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Absolute Maximum Ratings

(Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	65	mA
	*1 Peak forward current	I _{FM}	1	A
	Reverse Voltage	V _R	6	v
	Power dissipation	P	100	mW
Output	Supply voltage	V _{CC}	7	v
	Low level output current	I _{OL}	20	mA
	Power dissipation	P _O	250	mW
Operating temperature		T _{opr}	0 to +70	°C
Storage temperature		T _{stg}	-40 to +80	°C
*2 Soldering temperature		T _{sol}	260	°C

*1 Pulse width ≤ 100 μs, Duty ratio = 0.01

*2 For 5 seconds

Electro-optical Characteristics

(Unless otherwise specified, $T_a=0$ to $+70^\circ\text{C}$)

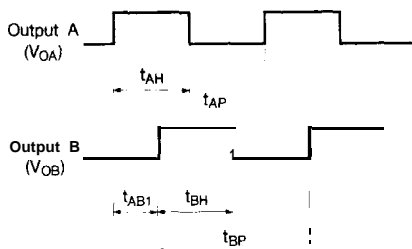
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F	$T_a=25^\circ\text{C}$, $I_F=30\text{mA}$	—	1.2	1.5	V
	Reverse current	I_R	$T_a=25^\circ\text{C}$, $V_R=3\text{V}$	—		10	μA
Output	Operating supply voltage	V_{CC}		4.5	5.0	5.5	V
	High level output voltage	V_{OH}	*3 $V_{CC}=5\text{V}$, $I_F=30\text{mA}$	2.4	4.9	—	V
	Low level output voltage	V_{OL}	*3 $I_{OL}=8\text{mA}$, $V_{CC}=5\text{V}$, $I_F=30\text{mA}$	—	0.1	0.4	V
	Supply current	I_{CC}	*3 *4 $I_F=30\text{mA}$, $V_{CC}=5\text{V}$	—	5	20	mA
Transfer characteristics	Duty ratio	D_A *5	$V_{CC}=5\text{V}$, $I_F=30\text{mA}$, $f=2.5\text{kHz}$	20	50	80	%
		D_B *5		20	50	80	%
	Response frequency	f_{MAX}	*3 $V_{CC}=5\text{V}$, $I_F=30\text{mA}$	—		5	kHz

*3 Measured under the condition shown in Measurement Condition

*4 In the condition that output A and B are low level.

*5 $D_A = \frac{t_{AH}}{t_{AP}} \times 100$, $D_B = \frac{t_{BH}}{t_{BP}} \times 100$

Output Waveforms



Rotational direction : Counterclockwise when seen from OPIC light detector

Fig. 1 Forward Current vs. Ambient Temperature

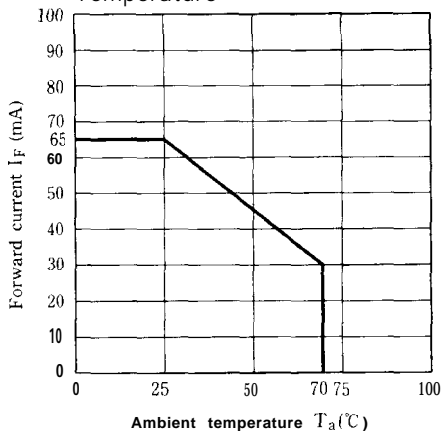


Fig. 2 output Power Dissipation vs. Ambient Temperature

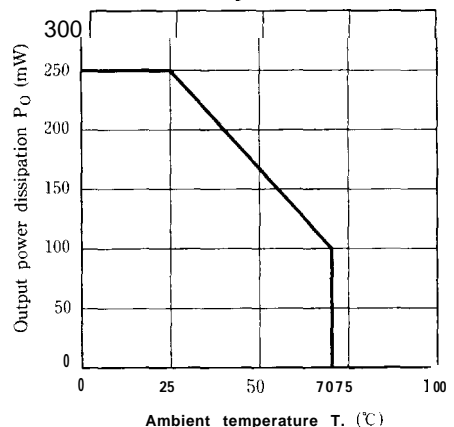


Fig. 3 Duty Ratio vs. Frequency

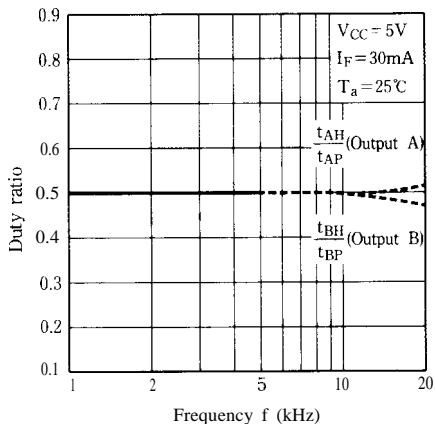


Fig. 4 Phase Difference vs. Frequency Temperature

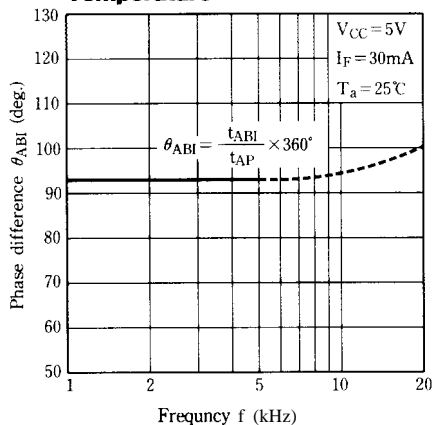


Fig. 5 Duty Ratio vs. Ambient Temperature

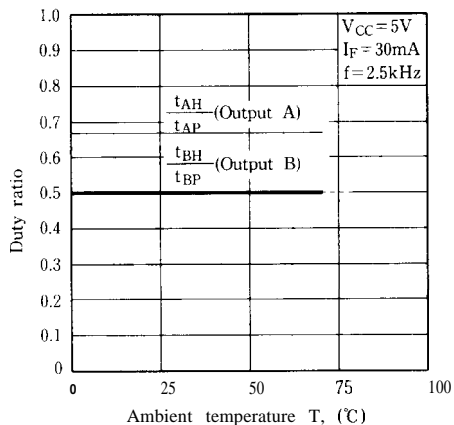


Fig. 6 Phase Difference vs. Ambient Temperature

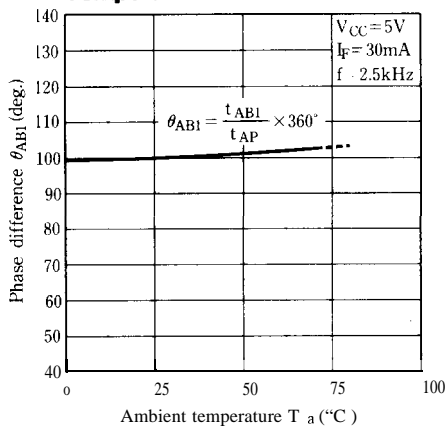


Fig. 7 Duty Ratio vs. Distance (X direction)

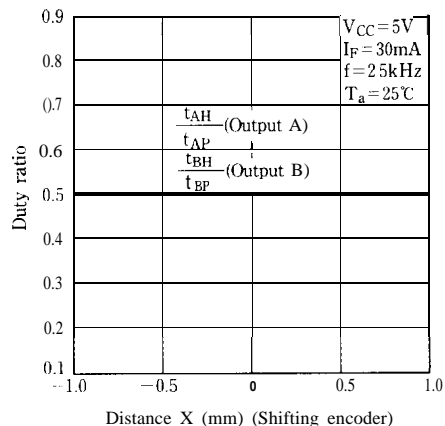


Fig. 8 Phase Difference vs. Distance (X direction)

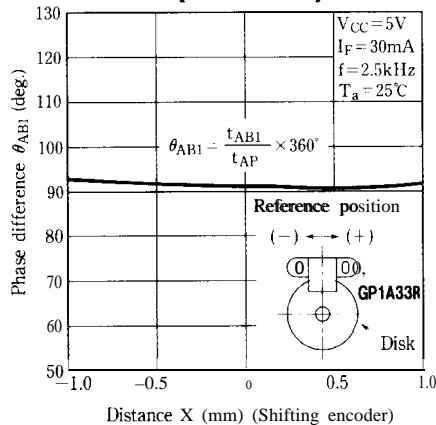


Fig. 9 Duty Ratio vs. Distance (Y direction)

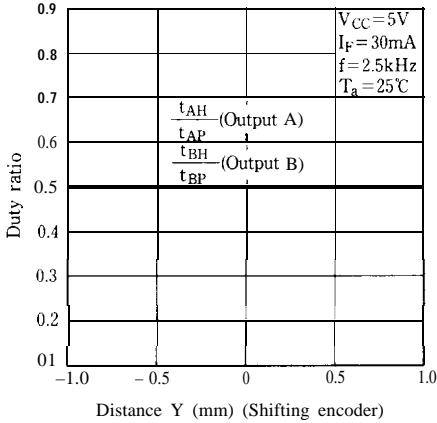


Fig.10 Phase Difference vs. Distance (Y direction)

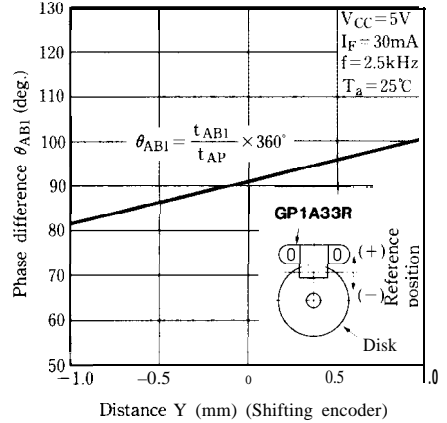


Fig.11 Duty Ratio vs. Distance (Z direction)

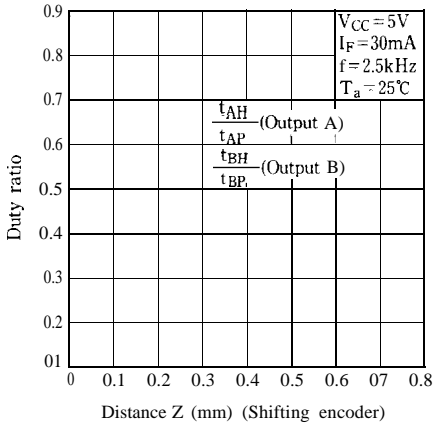
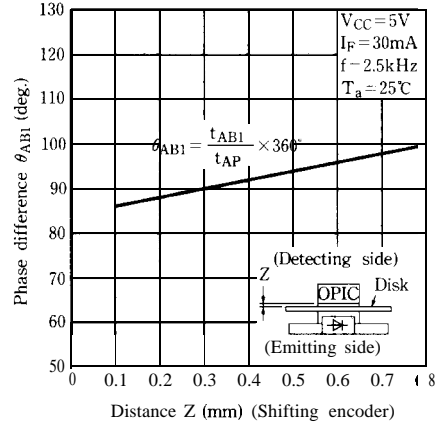
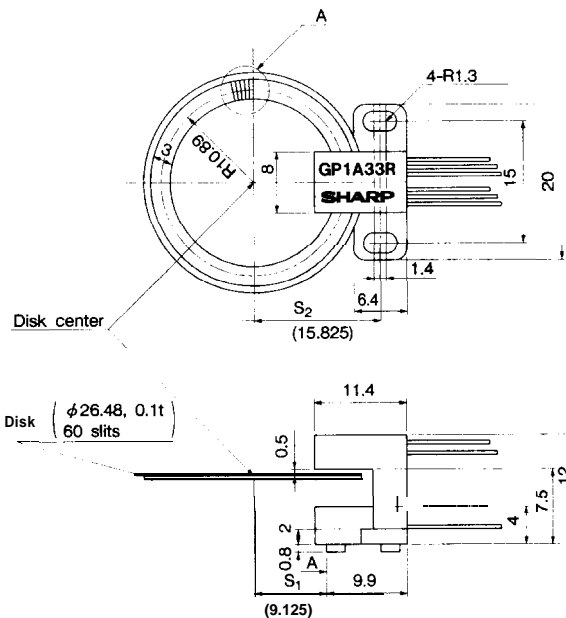


Fig.12 Phase Difference vs. Distance (Z direction)



Measurement Conditions



(Basic Design)

R_0 (distance between the disk center and half point of a slit),
 P (slit pitch), S_1 and S_2 (installing position of photointerrupter) will be provided by the following equations.
 Slit pitch : P (slit center)

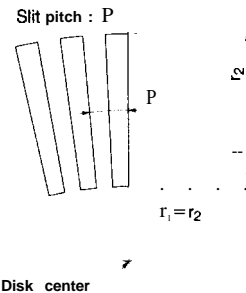
$$R_0 = \frac{N}{60} \times 10.89 \text{ (mm)} \quad N : \text{number of slits}$$

$$P = \frac{2 \times \pi \times R_0}{N} \text{ (mm)}$$

$$S_1 = R_0 - 1.765 \text{ (mm)}, \quad S_2 = S_1 + 6.7 \text{ (mm)}$$

Note) When the number of slits is changed, values in parenthesis are also changed according to the number.

Enlarged drawing (Ex.) In the case of $N = 100/P/R$



$$R() = \frac{100}{60} \times 10.89 \text{ (mm)}$$

$$= 18.15 \text{ mm}$$

$$P = \frac{2 \times \pi \times 18.15}{100}$$

$$= 1.14 \text{ mm}$$

$$S_1 = 18.15 - 1.765$$

$$= 16.385 \text{ mm}$$

$$S_2 = 16.385 + 6.7$$

$$= 23.085 \text{ mm}$$

■ Precautions for Use

- (1) This module is designed to be operated at $I_F = 30 \text{ mA}$ TYP.
- (2) Fixing torque : MAX. $6 \text{ kg} \cdot \text{cm}$
- (3) In order to stabilize power supply line, connect a by-pass capacitor of more than $0.01 \mu \text{ F}$ between Vcc and GND near the device.
- (4) As for other general cautions, refer to the chapter "Precautions for Use" (Page 78 to 93)

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